



# Schottky Diode

$$V_{RRM} = 8\text{ V}$$

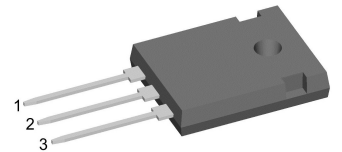
$$I_{FAV} = 2 \times 40\text{ A}$$

$$V_F = 0.28\text{ V}$$

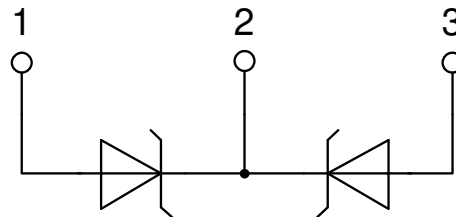
High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

Part number

**DSSK80-0008D**



Backside: cathode



### Features / Advantages:

- Very low  $V_f$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

### Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

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| Schottky   |  |  |   | Ratings                     |      |      |      |
|------------|--|--|---|-----------------------------|------|------|------|
| Symbol     | Definition                                   | Conditions                                   |   | min.                        | typ. | max. | Unit |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |  |   |                             |      | 8    | V    |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |  |   |                             |      | 8    | V    |
| $I_R$      | reverse current, drain current               | $V_R = 8\text{ V}$                           | $T_{VJ} = 25^\circ\text{C}$             |                             |      | 70   | mA   |
|            |  | $V_R = 8\text{ V}$                           | $T_{VJ} = 100^\circ\text{C}$            |                             |      | 1250 | mA   |
| $V_F$      | forward voltage drop                         | $I_F = 40\text{ A}$                          | $T_{VJ} = 25^\circ\text{C}$             |                             |      | 0.37 | V    |
|            |  | $I_F = 80\text{ A}$                          |   |                             |      | 0.49 | V    |
|            |  | $I_F = 40\text{ A}$                          | $T_{VJ} = 125^\circ\text{C}$            |                             |      | 0.28 | V    |
|            |  | $I_F = 80\text{ A}$                          |   |                             |      | 0.43 | V    |
| $I_{FAV}$  | average forward current                      | $T_C = 130^\circ\text{C}$<br>rectangular     | $T_{VJ} = 150^\circ\text{C}$<br>d = 0.5 |                             |      | 40   | A    |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only            |   |                             |      | 0.10 | V    |
| $r_F$      | slope resistance                             |  |   |                             |      | 3.8  | mΩ   |
| $R_{thJC}$ | thermal resistance junction to case          |  |   |                             |      | 0.8  | K/W  |
| $R_{thCH}$ | thermal resistance case to heatsink          |  |   |                             | 0.25 |      | K/W  |
| $P_{tot}$  | total power dissipation                      |  |   | $T_C = 25^\circ\text{C}$    |      | 155  | W    |
| $I_{FSM}$  | max. forward surge current                   | t = 10 ms; (50 Hz), sine; $V_R = 0\text{ V}$ |   | $T_{VJ} = 45^\circ\text{C}$ |      | 1.00 | kA   |
| $C_J$      | junction capacitance                         | $V_R = 1\text{ V}$ f = 1 MHz                 |   | $T_{VJ} = 25^\circ\text{C}$ |      | 13.1 | nF   |



| Package TO-247 |                              |                            | Ratings |      |      |      |
|----------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions                 | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal <sup>1)</sup> |         |      | 70   | A    |
| $T_{VJ}$       | virtual junction temperature |                            | -55     |      | 150  | °C   |
| $T_{op}$       | operation temperature        |                            | -55     |      | 125  | °C   |
| $T_{stg}$      | storage temperature          |                            | -55     |      | 150  | °C   |
| <b>Weight</b>  |                              |                            |         | 6    |      | g    |
| $M_D$          | mounting torque              |                            | 0.8     |      | 1.2  | Nm   |
| $F_C$          | mounting force with clip     |                            | 20      |      | 120  | N    |

**Product Marking**



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSSK80-0008D    | DSSK80-0008D       | Tube          | 30       | 492906   |

**Equivalent Circuits for Simulation**

*\* on die level*

$T_{VJ} = 150^{\circ}C$



**Schottky**

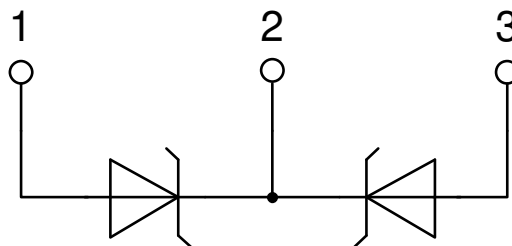
|              |                    |     |    |
|--------------|--------------------|-----|----|
| $V_{0\ max}$ | threshold voltage  | 0.1 | V  |
| $R_{0\ max}$ | slope resistance * | 1.3 | mΩ |



**Outlines TO-247**



| Sym. | Inches    |       | Millimeter |       |
|------|-----------|-------|------------|-------|
|      | min.      | max.  | min.       | max.  |
| A    | 0.185     | 0.209 | 4.70       | 5.30  |
| A1   | 0.087     | 0.102 | 2.21       | 2.59  |
| A2   | 0.059     | 0.098 | 1.50       | 2.49  |
| D    | 0.819     | 0.845 | 20.79      | 21.45 |
| E    | 0.610     | 0.640 | 15.48      | 16.24 |
| E2   | 0.170     | 0.216 | 4.31       | 5.48  |
| e    | 0.215 BSC |       | 5.46 BSC   |       |
| L    | 0.780     | 0.800 | 19.80      | 20.30 |
| L1   | -         | 0.177 | -          | 4.49  |
| Ø P  | 0.140     | 0.144 | 3.55       | 3.65  |
| Q    | 0.212     |       | 5.38       |       |
| S    | 0.242 BSC |       | 6.14 BSC   |       |
| b    | 0.039     | 0.055 | 0.99       | 1.40  |
| b2   | 0.065     | 0.094 | 1.65       | 2.39  |
| b4   | 0.102     | 0.135 | 2.59       | 3.43  |
| c    | 0.015     | 0.035 | 0.38       | 0.89  |
| D1   | 0.515     | -     | 13.07      | -     |
| D2   | 0.020     | 0.053 | 0.51       | 1.35  |
| E1   | 0.530     | -     | 13.45      | -     |
| Ø P1 | -         | 0.29  | -          | 7.39  |



**Schottky**

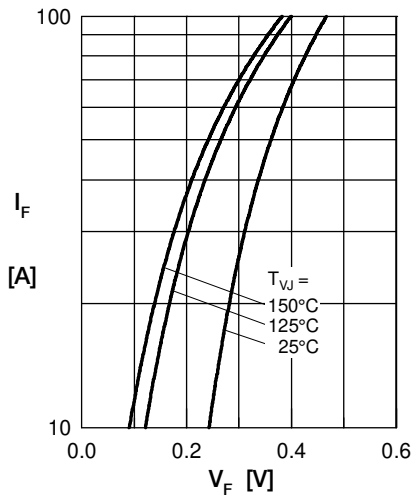


Fig. 1 Max. forward voltage drop characteristics

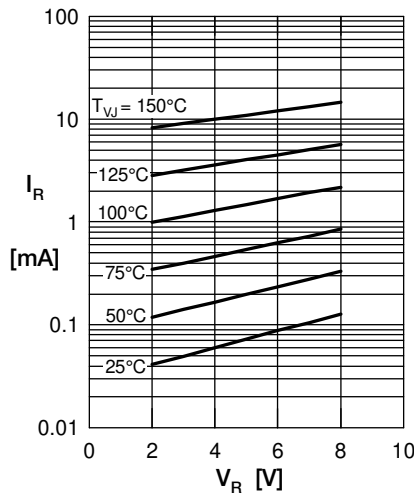


Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$

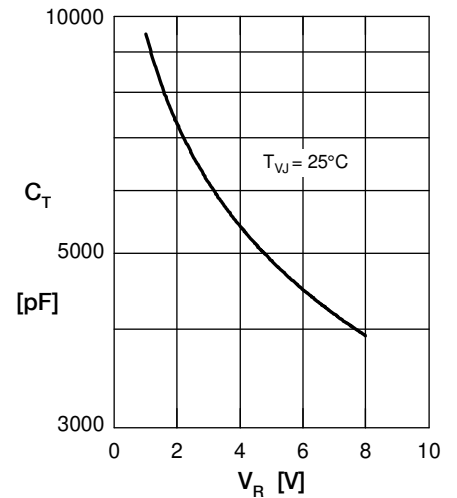


Fig. 3 Typ. junction capacitance  $C_T$  vs. reverse voltage  $V_R$

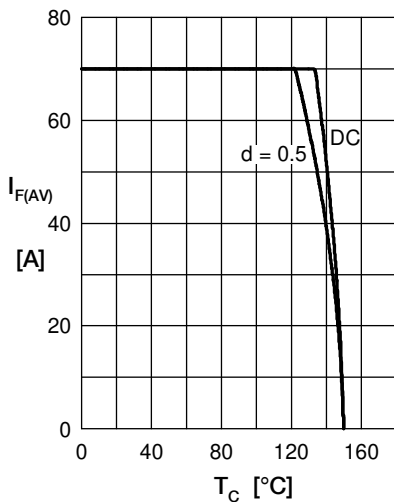


Fig. 4 Average forward current  $I_{F(AV)}$  vs. case temp.  $T_C$

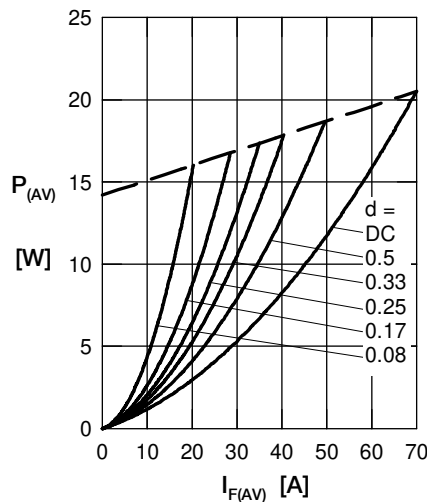


Fig. 5 Forward power loss characteristics

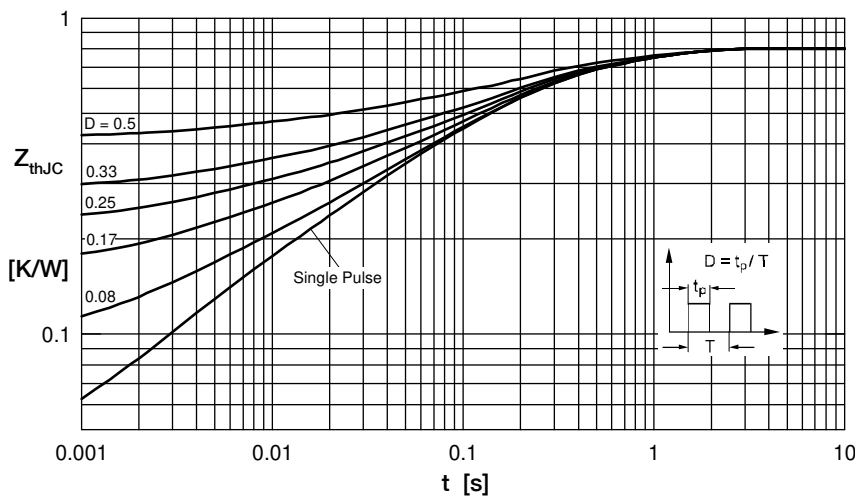


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode

单击下面可查看定价，库存，交付和生命周期等信息

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